RFMD + TriQuint = Qorvo

# SGC-6389Z

# 50MHz to 4000MHz ACTIVE BIAS SILICON GERMANIUM CASCADABLE GAIN BLOCK

Package: SOT-89

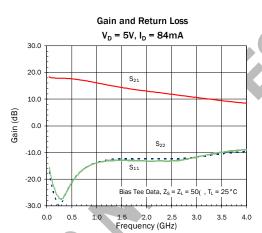




## **Product Description**

RFMD's SGC-6389Z is a high performance SiGe HBT MMIC amplifier utilizing a Darlington configuration with a patented active-bias network. The active bias network provides stable current over temperature and process Beta variations. Designed to run directly from a 5V supply, the SGC-6389Z does not require a dropping resistor as compared to traditional Darlington amplifiers. The SGC-6389Z product is designed for high linearity 5V gain block applications that require small size and minimal external components. It is internally matched to  $50\Omega$ .





#### **Features**

- Single Fixed 5V Supply
- No Dropping Resistor Required
- Patented Self Bias Circuitry
- Gain = 12.8dBm at 1950MHz
- P1dB = 18.6dBm at 1950MHz
- OIP3 = 34.5dBm at 1950MHz
- Robust 1000V ESD, Class 1C HBM

### **Applications**

- PA Driver Amplifier
- Cellular, PCS, GSM, UMTS, WCDMA
- IF Amplifier
- Wireless Data, Satellite

	Specification					
Parameter	Min.	Min. Typ.		Unit	Condition	
Small Signal Gain	14.8	16.3	17.8	dB	850MHz	
	11.3	12.8	14.3	dB	1950MHz*	
		11.9		dB	2400MHz	
Output Power at 1dB Compression		19.5		dBm	850MHz	
	17.6	18.6		dBm	1950MHz*	
		18.2		dBm	2400MHz	
Output Third Order Intercept Point		36.0		dBm	850MHz	
	32.5	34.5		dBm	1950MHz*	
		33.5		dBm	2400MHz	
Input Return Loss	9.0	12.5		dB	1950MHz*	
Output Return Loss	8.5	11.5		dB	1950MHz*	
Noise Figure		3.7	4.5	dB	1950MHz	
Thermal Resistance		60		°C/W	junction - lead	
Device Operating Voltage		5.0		V		
Device Operating Current	74.0	84.0	94.0	mA		

Test Conditions:  $V_D = 5V$ ,  $I_D = 84$ mA Typ., OIP3 Tone Spacing = 1MHz,  $P_{OUT}$  per tone = 0dBm, Bias Tee Data,  $Z_S = Z_L = 50\Omega$ ,

<sup>\*</sup>Test results at 1950MHz measured with Application Circuit



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#### **Absolute Maximum Ratings**

Parameter	Rating	Unit
Device Current (I <sub>CE</sub> )	120	mA
Device Voltage (V <sub>CE</sub> )	6.5	V
RF Input Power* (See Note)	8	dBm
Junction Temp (T <sub>J</sub> )	+150	°C
Operating Temp Range (T <sub>L</sub> )	-40 to +85	°C
Storage Temp	+150	°C
ESD Rating - Human Body Model (HBM)	Class 1C	
Moisture Sensitivity Level	MSL 2	

<sup>\*</sup>Note: Load condition  $Z_L = 50\Omega$ .

Operation of this device beyond any one of these limits may cause permanent damage. For reliable continuous operation, the device voltage and current must not exceed the maximum operating values specified in the table on page one.

Bias Conditions should also satisfy the following expression:



#### Caution! ESD sensitive device.

Exceeding any one or a combination of the Absolute Maximum Rating conditions may cause permanent damage to the device. Extended application of Absolute Maximum Rating conditions to the device may reduce device reliability. Specified typical performance or functional operation of the device under Absolute Maximum Rating conditions to the device may reduce the device under Absolute Maximum Rating conditions to the device may reduce the device under Absolute Maximum Rating conditions to the device under Absolute Maximum Rating co tions is not implied.

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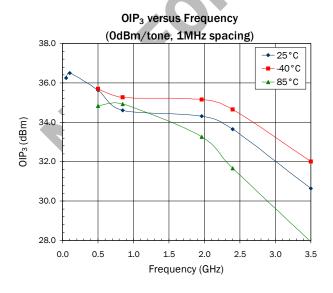
RFMD Green: RoHS compliant per EU Directive 2002/95/EC, halogen free per IEC 61249-2-21, < 1000ppm each of antimony trioxide in polymeric materials and red phosphorus as a flame retardant, and <2% antimony in solder.

#### Typical RF Performance at Key Operating Frequencies (Bias Tee Data)

Parameter	Unit	50	100	500	850	1950	2400	3500
		MHz	MHz	MHz	MHz	MHz*	MHz	MHz
Small Signal Gain (G)	dB	18.4	18.0	17.6	16.3	12.8	11.9	9.4
Output Third Order Intercept Point (OIP <sub>3</sub> )	dBm	36.0	36.5	35.5	36.0	34.5	33.5	30.5
Output Power at 1dB Compression (P <sub>1dB</sub> )	dBm	20.7	20.4	19.9	19.5	18.6	18.2	16.5
Input Return Loss (IRL)	dB	17.5	23.0	21.5	15.5	12.5	12.0	10.5
Output Return Loss (ORL)	dB	15.5	21.0	22.0	15.5	11.5	12.0	10.0
Reverse Isolation (S <sub>12</sub> )	dB	20.5	20.0	21.0	21.5	19.5	19.0	18.5
Noise Figure (NF)	dB	2.8	2.6	2.9	3.3	3.7	4.0	4.7

Test Conditions:  $V_D = 5V - I_D = 84mA - OIP3$  Tone Spacing = 1MHz,  $P_{OUT}$  per tone = 0dBm  $T_L = 25 \,^{\circ}\text{C} - Z_S = Z_L = 50 \,^{\circ}\Omega$  \*Test results at 1950MHz measured with Application Circuit

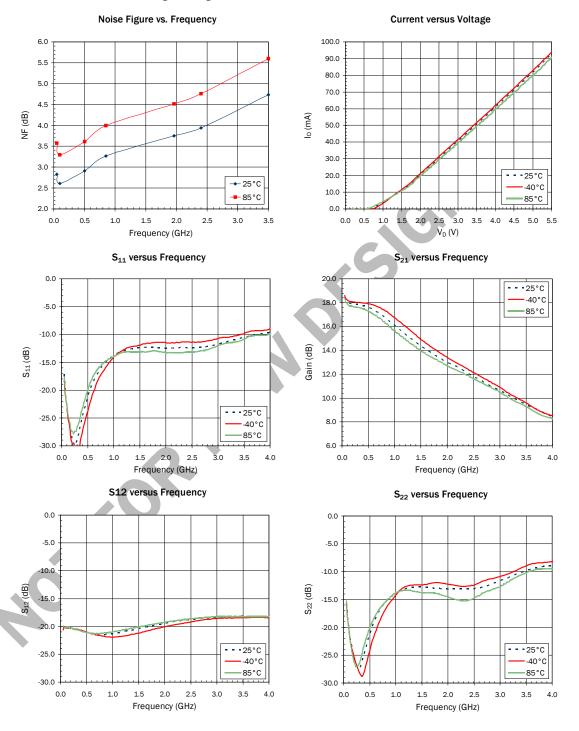
#### Typical Performance with Bias Tees, $V_D = 5V$ , $I_D = 84mA$



#### P<sub>1dB</sub> versus Frequency 23.0 → 25°C -40°C 21.0 --- 85°C 19.0 P<sub>1dB</sub> (dBm) 17.0 15.0 13.0 0.0 0.5 1.0 1.5 2.0 2.5 3.0 3.5 Frequency (GHz)

 $I_DV_D < (T_J - T_L)/R_{TH}$ , j - I and  $T_L = T_{LEAD}$ 

## Typical Performance with Bias Tees, $V_D = 5V$ , $I_D = 84mA$



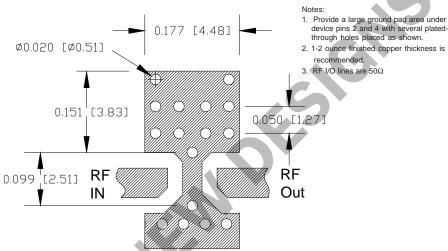


Pin	Function	Description
1	RF IN	RF input pin. This pin requires the use of an external DC blocking capacitor chosen for the frequency of operation.
2, 4	GND	Connection to ground. Use via holes as close to the device ground leads as possible to reduce ground inductance and achieve optimum RF performance.
3	RF OUT/DC BIAS	RF output and bias pin. This pin requires the use of an external DC blocking capacitor chosen for the frequency of operation.

# **SOT-89 PCB Pad Layout**

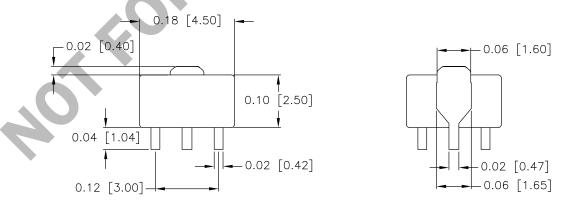
#### SOT-89 PCB Pad Layout

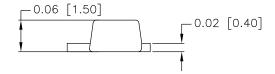
Dimensions in inches [millimeters]



# **SOT-89 Nominal Package Dimensions**

Dimensions in inches (millimeters)
Refer to drawing posted at www.rfmd.com for tolerances.

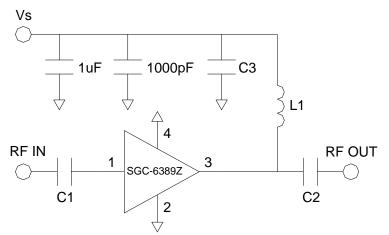




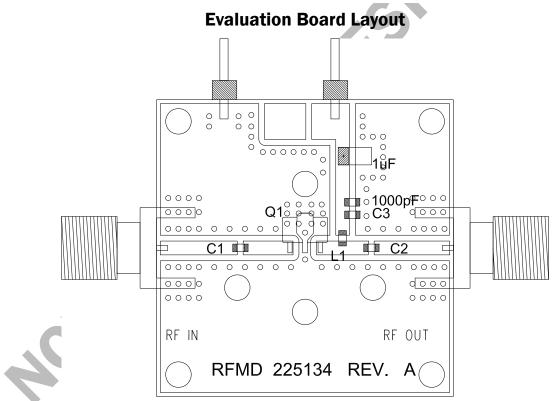


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# **Application Schematic**

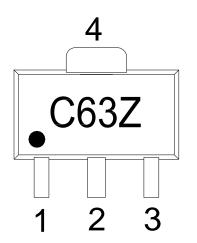


Application Circuit Element Values				
Reference Designator	100-1000MHz 1000-2200MH			
C1	1000pF	6.8pF		
C2	100pF	6.8pF		
СЗ	100pF	6.8pF		
L1	100nH	39nH		





## **Part Identification**



Alternate marking "SGC6389Z" on line one with Trace Code on line two.

Part / Evaluation Board Ordering Information					
Part Number	Reel Size	Devices / Reel			
SGC-6389Z	Lead Free, RoHs Compliant	13"	3000		
SGC-6389Z-EVB1	100-1000 MHz Evaluation Board	N/A	N/A		
SGC-6389Z-EVB2	1000-2200 MHz Evaluation Board	N/A	N/A		